VSMY3940X01



Vishay Semiconductors

High Speed Infrared Emitting Diode, 940 nm, Surface Emitter Technology



As part of the <u>SurfLight</u>[™] portfolio, the VSMY3940X01 is an infrared, 940 nm emitting diode based on surface emitter

technology with high radiant intensity, high optical power

and high speed, molded in a PLCC-2 package for surface

FEATURES

- Package type: surface mount
- Package form: PLCC-2
- Dimensions (L x W x H in mm): 3.5 x 2.8 x 1.75
- AEC-Q101 gualified
- Peak wavelength: $\lambda_p = 940 \text{ nm}$
- High reliability
- · High radiant power
- · High radiant intensity
- Angle of half intensity: $\varphi = \pm 60^{\circ}$
- Suitable for high pulse current operation
- Floor life: 168 h, MSL 3, acc. J-STD-020
- Lead (Pb)-free reflow soldering
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RELEASED FOR APPLICATIONS

Infrared radiation source for operation with CMOS cameras (illumination)

- High speed IR data transmission
- · IR touch panels
- 3D TV
- · Light curtain

PRODUCT SUMMARY COMPONENT l_e (mW/sr) λ_P (nm) φ (deg) t_r (ns) VSMY3940X01 15 ± 60 940 10

Note

DESCRIPTION

mounting (SMD).

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION							
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM				
VSMY3940X01-GS08	Tape and reel	MOQ: 7500 pcs, 1500 pcs/reel	PLCC-2				
VSMY3940X01-GS18	Tape and reel	MOQ: 8000 pcs, 8000 pcs/reel	PLCC-2				

Note

· MOQ: minimum order quantity

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RoHS COMPLIANT HALOGEN FREE

GREEN (5-2008)

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ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Reverse voltage		V _R	5	V			
Forward current		I _F	100	mA			
Pulse peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA			
Surge forward current	t _p = 100 μs	I _{FSM}	1	A			
Power dissipation		Pv	190	mW			
Junction temperature		Tj	100	°C			
Operating temperature range		T _{amb}	-40 to +85	°C			
Storage temperature range		T _{stg}	-40 to +100	°C			
Soldering temperature	acc. figure 10, J-STD-020	T _{sd}	260	°C			
Thermal resistance junction/ambient	J-STD-051, soldered on PCB	R _{thJA}	250	K/W			



Fig. 1 - Power Dissipation Limit vs. Ambient Temperature



Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Forward voltage	l _F = 100 mA, t _p = 20 ms	V _F		1.44	1.9	V		
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	V _F		2.2		V		
Temperature coefficient of V_F	I _F = 100 mA	TK _{VF}		-1.6		mV/K		
Reverse current		I _R	not designed for reverse operation			μA		
Junction capacitance	V _R = 0 V, f = 1 MHz, E = 0	Cj		125		pF		
Radiant intensity	l _F = 100 mA, t _p = 20 ms	l _e	8	15	24	mW/sr		
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	l _e		120		mW/sr		
Radiant power	l _F = 100 mA, t _p = 20 ms	фe		55		mW		
Temperature coefficient of ϕ_{e}	I _F = 100 mA	TKφ _e		-0.25		%/K		
Angle of half intensity		φ		± 60		deg		
Peak wavelength	I _F = 20 mA	λρ	920	940	960	nm		
Spectral bandwidth	I _F = 30 mA	Δλ		40		nm		
Temperature coefficient of λ_p	I _F = 100 mA	ΤΚλ _ρ		0.25		nm/K		
Rise time	I _F = 100 mA	t _r		10		ns		
Fall time	I _F = 100 mA	t _f		10		ns		

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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)



Fig. 3 - Forward Current vs. Forward Voltage



Fig. 4 - Forward Voltage vs. Ambient Temperature



Fig. 5 - Relative Forward Voltage vs. Ambient Temperature



Fig. 6 - Radiant Intensity vs. Forward Current



Fig. 7 - Relative Radiant Intensity vs. Ambient Temperature



Fig. 8 - Relative Radiant Intensity vs. Wavelength

3 For technical questions, contact: <u>emittertechsupport@vishay.com</u>

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Fig. 9 - Relative Radiant Intensity vs. Angular Displacement

PACKAGE DIMENSIONS in millimeters









Mounting Pad Layout

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SOLDER PROFILE



Fig. 10 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label: Floor life: 168 h Conditions: $T_{amb} < 30$ °C, RH < 60 % Moisture sensitivity level 3, acc. to J-STD-020.

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

TAPE AND REEL

PLCC-2 components are packed in antistatic blister tape (DIN IEC (CO) 564) for automatic component insertion. Cavities of blister tape are covered with adhesive tape.





Fig. 12 - Tape Dimensions in mm for PLCC-2

MISSING DEVICES

A maximum of 0.5 % of the total number of components per reel may be missing, exclusively missing components at the beginning and at the end of the reel. A maximum of three consecutive components may be missing, provided this gap is followed by six consecutive components.





The tape leader is at least 160 mm and is followed by a carrier tape leader with at least 40 empty compartments. The tape leader may include the carrier tape as long as the cover tape is not connected to the carrier tape. The least component is followed by a carrier tape trailer with a least 75 empty compartments and sealed with cover tape.



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The removal force lies between 0.1 N and 1.0 N at a removal speed of 5 mm/s. In order to prevent components from popping out of the blisters, the cover tape must be pulled off at an angle of 180° with regard to the feed direction.



Fig. 15 - Dimensions of Reel-GS18



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